



#### N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	<b>I</b> D T <sub>A</sub> = +25°C
	3Ω @ V <sub>GS</sub> = 4.5V	0.3A
20V	4Ω @ V <sub>GS</sub> = 2.5V	0.26A
	6Ω @ V <sub>GS</sub> = 1.8V	0.21A

## **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- DC-DC Converters
- Load Switch

Notes:

Power Management Functions

### **Features and Benefits**

- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.0V Max
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN2991UTQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

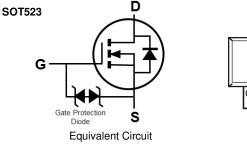
#### **Mechanical Data**

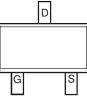
- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42
  Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)





Top View





Top View

## Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2991UTQ-7	SOT523	3000/Tape & Reel
DMN2991UTQ-13	SOT523	10000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

Date Code Key			ве5	 <u>▼</u> м	SOT523	$\frac{YM}{Y} = Da$	Product Typ ate Code M r (ex: H = 2 nth (ex: 9 =	larking 2020)				
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Н	I	J	K	L	М	N	0	Р	R	S	Т
Manah	lan	Fak	Мак	A	Max	l	l. d	Διια	Sep	Oct	Nov	Dec
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	001	NOV	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



#### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Cha	racteristic		Symbol	Value	Unit
Drain-Source Voltage			VDSS	20	V
Gate-Source Voltage			V <sub>GSS</sub>	±10	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 4.5V	Steady $T_A = +25^{\circ}C$ State $T_A = +75^{\circ}C$		D	0.3 0.24	A
Maximum Continuous Body Diode Forward Current (Note 6)			ls	0.3	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	1.4	A

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.28	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	439	°C/W
Total Power Dissipation (Note 6)		PD	0.43	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	291	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

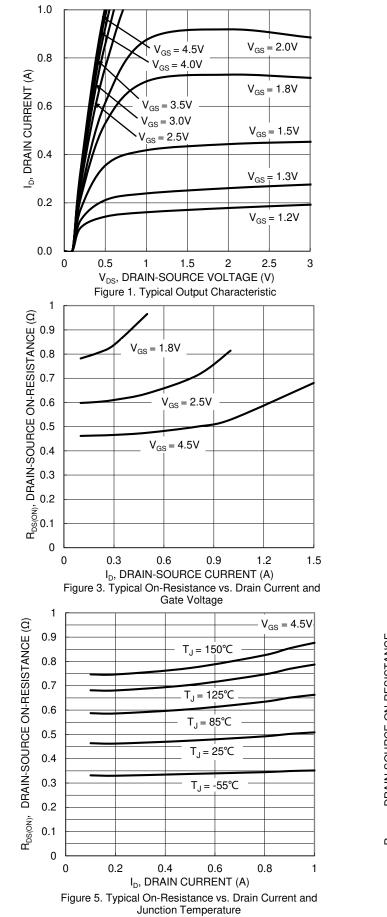
			_			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						-
Drain-Source Breakdown Voltage	BVDSS	20	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS		—	1	μA	$V_{DS} = 16V, V_{GS} = 0V$
Gate-Source Leakage	IGSS		—	±10	μA	$V_{GS} = \pm 5V, \ V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.5	—	1.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
			0.4	3.0		$V_{GS} = 4.5V, I_D = 100mA$
Static Drain-Source On-Resistance	Bracow		0.6	4.0	Ω	$V_{GS} = 2.5V, I_D = 50mA$
Static Drain-Source On nesistance	RDS(ON)		0.8	6.0		$V_{GS} = 1.8V, I_{D} = 20mA$
		_	1.0	10.0		$V_{GS} = 1.5V, I_{D} = 10mA$
Diode Forward Voltage	V <sub>SD</sub>	_	0.8	1.0	V	$V_{GS} = 0V, I_{S} = 150mA$
DYNAMIC CHARACTERISTICS (Note 8)	-					•
Input Capacitance	Ciss	_	21.5	_	pF	
Output Capacitance	Coss	_	4.9	_	pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	3.7	_	pF	
Gate Resistance	Rg		0.94	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge	Qg		0.35	_	nC	
Gate-Source Charge	Qgs	_	0.07	_	nC	VGS = 4.5V, VDS = 10V, ID = 250mA
Gate-Drain Charge	Q <sub>gd</sub>	_	0.08	_	nC	
Turn-On Delay Time	td(on)	_	5.6	—	ns	
Turn-On Rise Time	tR	_	4.9		ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	60.6		ns	$R_{L} = 47\Omega, R_{g} = 10\Omega,$
Turn-Off Fall Time	tF	_	27.6	_	ns	I <sub>D</sub> = 200mA

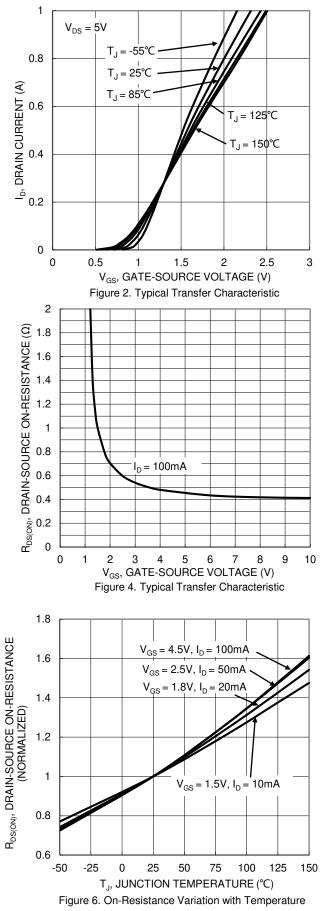
Notes: 5. Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.

Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.



#### DMN2991UTQ

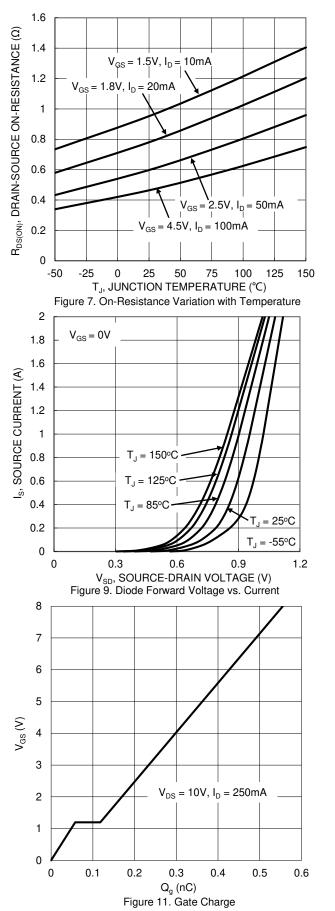


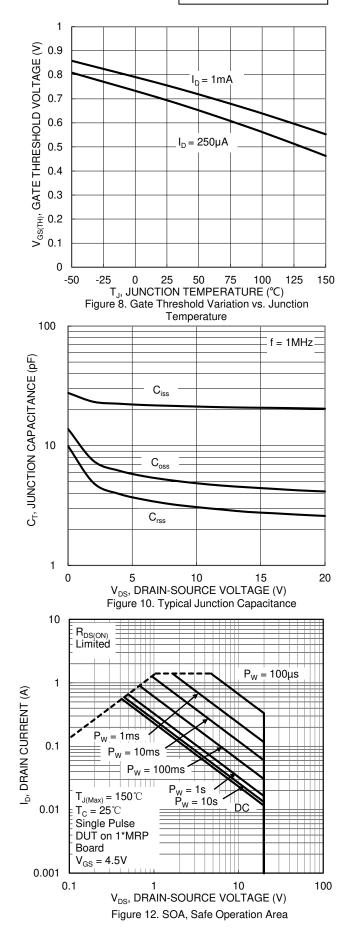


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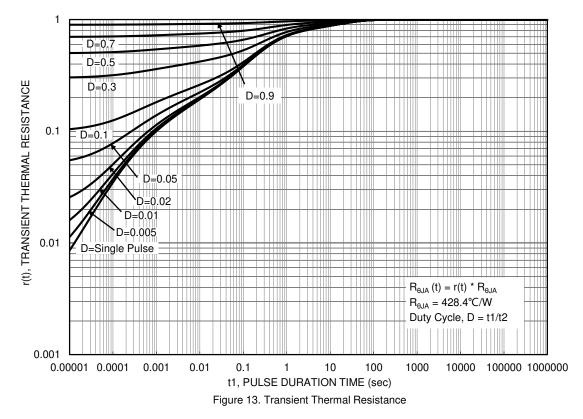






DMN2991UTQ Document number: DS42636 Rev. 2 - 2



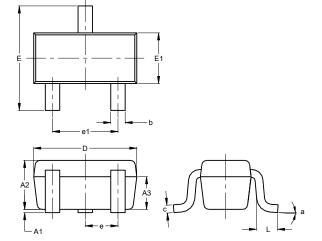




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

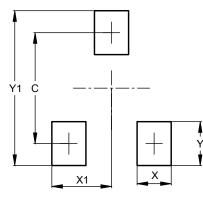




SOT523							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.60	0.80	0.75				
A3	0.45	0.65	0.50				
b	0.15	0.30	0.22				
С	0.10	0.20	0.12				
D	1.50	1.70	1.60				
Е	1.45	1.75	1.60				
E1	0.75	0.85	0.80				
е		0.50 BS	С				
e1	0.90	1.10	1.00				
L	0.20	0.40	0.33				
а	0°		8°				
Α	All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



#### SOT523

Dimensions	Value (in mm)
С	1.29
Х	0.40
X1	0.70
Y	0.51
Y1	1.80

DMN2991UTQ Document number: DS42636 Rev. 2 - 2



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